

Power Measurement Accuracy

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Power accuracy limitations

A typical (but by no means only) PSE power sensing and



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Power accuracy limitations



- PSE current accuracy has many components
 - R_S & V _{SS} IR drops
 - DAC INL and internal V_{REF} (typ. V_{BG} derived)
 - Op-amp V_{OFF}
- Reasonable assumptions can create variations as high as ±10%

– This error adds directly to un-utilized PSE power

- This does not take Vport variation into account
 - Added complexity for Power limitations

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Conclusion and Recommendations

- Consider implications on power measurement accuracy when selecting power classification levels
- Implementation & test costs increase with PSE power accuracy
- Recommendation
 - Fewer levels better than more

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